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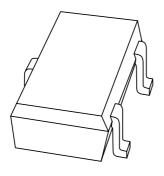
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Kind regards,

Team Nexperia

## DISCRETE SEMICONDUCTORS

# DATA SHEET



## PMSS3904 NPN switching transistor

Product data sheet Supersedes data of 1997 Sep 03 1999 May 27



## **NPN** switching transistor

PMSS3904

#### **FEATURES**

- Low current (max. 100 mA)
- Low voltage (max. 40 V).

#### **APPLICATIONS**

- General purpose switching and amplification
- Telephony and professional communication equipment.

#### **DESCRIPTION**

NPN switching transistor in an SC-70 (SOT323) plastic package. PNP complement: PMSS3906.

#### **MARKING CODE**

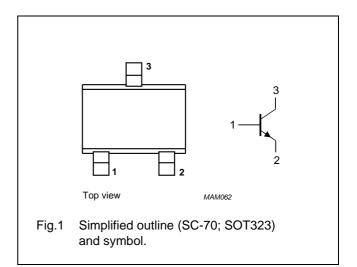
TYPE NUMBER	MARKING CODE <sup>(1)</sup>
PMSS3904	*04

#### Note

\* = - : Made in Hong Kong.
 \* = t : Made in Malaysia.

#### **PINNING**

PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	60	V
V <sub>CEO</sub>	collector-emitter voltage	open base	_	40	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	6	V
I <sub>C</sub>	collector current (DC)		_	100	mA
I <sub>CM</sub>	peak collector current		_	200	mA
I <sub>BM</sub>	peak base current		_	200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	200	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

## NPN switching transistor

PMSS3904

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	625	K/W

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

#### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	I <sub>E</sub> = 0; V <sub>CB</sub> = 30 V	_	50	nA
		I <sub>E</sub> = 0; V <sub>CB</sub> = 30 V; T <sub>j</sub> = 150 °C	_	10	μΑ
I <sub>EBO</sub>	emitter cut-off current	I <sub>C</sub> = 0; V <sub>EB</sub> = 5 V	_	50	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 1 V; see Fig.2			
		$I_C = 0.1 \text{ mA}$	40	_	
		I <sub>C</sub> = 1 mA	70	_	
		I <sub>C</sub> = 10 mA	100	300	
		I <sub>C</sub> = 50 mA; note 1	60	_	
		I <sub>C</sub> = 100 mA; note 1	30	_	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 1 mA	_	200	mV
		$I_C = 50 \text{ mA}; I_B = 5 \text{ mA}; \text{ note 1}$	_	300	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 1 mA	650	850	mV
		$I_C = 50 \text{ mA}; I_B = 5 \text{ mA}; \text{ note 1}$	_	950	mV
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0$ ; $V_{CB} = 5$ V; $f = 1$ MHz	_	4	pF
C <sub>e</sub>	emitter capacitance	$I_C = i_c = 0$ ; $V_{EB} = 0.5 \text{ V}$ ; $f = 1 \text{ MHz}$	_	12	pF
f <sub>T</sub>	transition frequency	$I_C = 10 \text{ mA}; V_{CE} = 20 \text{ V}; f = 100 \text{ MHz}$	180	-	MHz
F	noise figure	$I_C$ = 100 μA; $V_{CE}$ = 5 V; $R_S$ = 1 kΩ $f$ = 10 Hz to 15.7 KHz	_	5	dB
Switching t	imes (between 10% and 90% levels	); see Fig.3			
t <sub>on</sub>	turn-on time	I <sub>Con</sub> = 10 mA; I <sub>Bon</sub> = 1 mA;	_	110	ns
t <sub>d</sub>	delay time	$I_{Boff} = -1 \text{ mA}; V_{CC} = 3 \text{ V};$	_	50	ns
t <sub>r</sub>	rise time	$V_{BB} = -1.9 \text{ V}$	_	60	ns
t <sub>off</sub>	turn-off time		_	1200	ns
t <sub>s</sub>	storage time		_	1000	ns
t <sub>f</sub>	fall time		_	200	ns

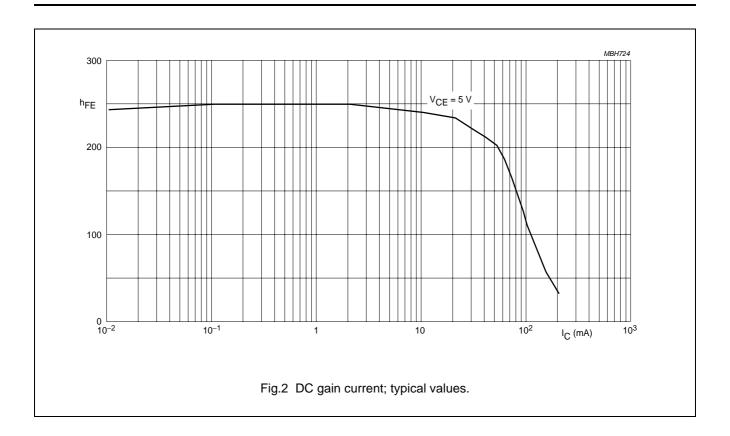
#### Note

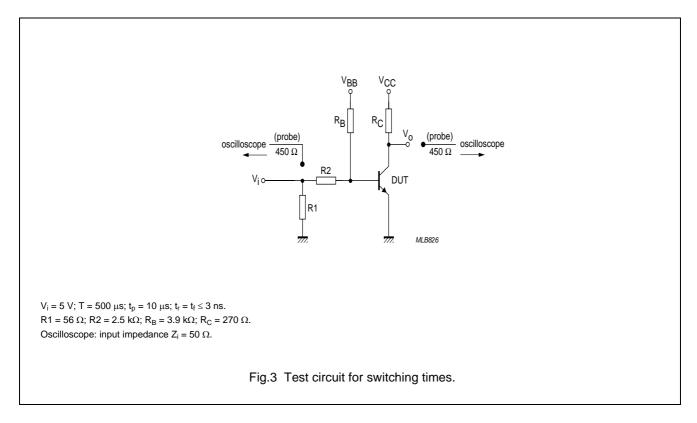
1. Pulse test:  $t_p \leq 300~\mu s;~\delta \leq 0.02.$ 

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## NPN switching transistor

## PMSS3904





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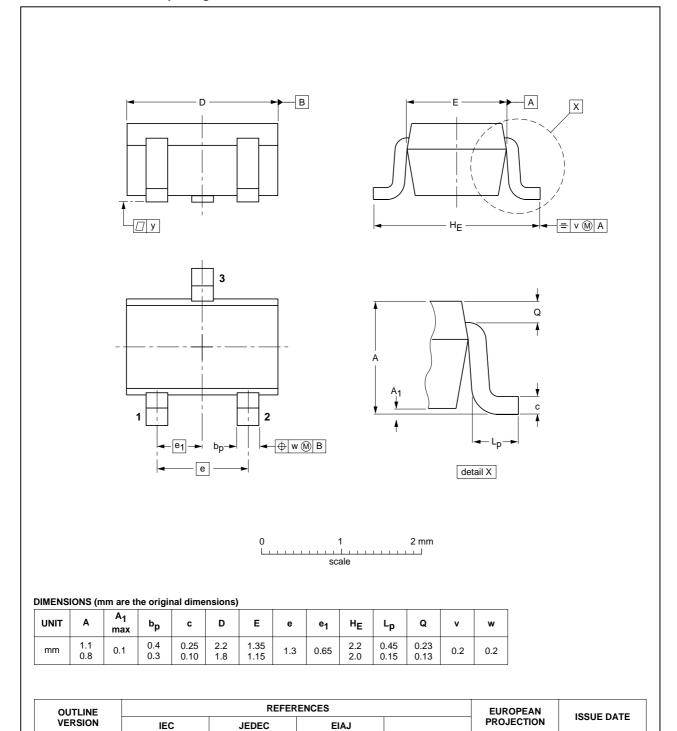
## NPN switching transistor

PMSS3904

#### **PACKAGE OUTLINE**

Plastic surface mounted package; 3 leads

**SOT323** 



SC-70

97-02-28

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SOT323

### **NPN** switching transistor

PMSS3904

#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### **Notes**

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